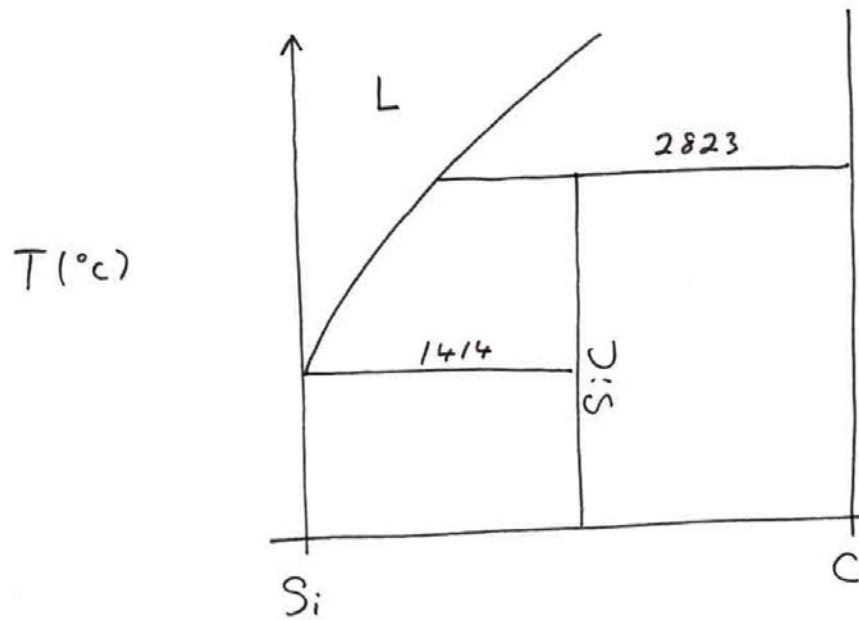


# 3.020 Lecture 32

Prof. Rafael Jaramillo

# 1 Reacting systems with condensed and gaseous phases

Example : Formation of SiC

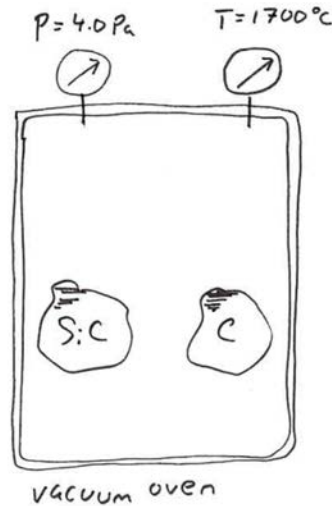


## 2 Problem statement

- Place pieces of SiC and C into a vacuum oven
- Pull vacuum (to  $P \approx 0 \text{ Pa}$ ), seal, and then heat to  $1700 \text{ }^\circ\text{C}$

You observe:

1. SiC and C are both still present
2. Pressure  $P = 4.0 \text{ Pa}$




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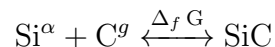
## 3 Reference data

- Saturation vapor pressures at  $1700 \text{ }^\circ\text{C}$  are

$$P_{Si}^{SAT}(1700 \text{ }^\circ\text{C}) = 4.4 \text{ Pa}$$

$$P_C^{SAT}(1700 \text{ }^\circ\text{C}) \approx P_{SiC}^{SAT}(1700 \text{ }^\circ\text{C}) \approx 0 \text{ Pa}$$

Question: What is the Gibbs free energy of formation of SiC at  $1700 \text{ }^\circ\text{C}$  ?



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$$\Delta_f G_{SiC} = G_{SiC} - G_{Si}^o - G_c^o$$

**For 1 mole of SiC**

$$G' = \sum_i n_i^{SiC} \mu_i^{SiC} = \mu_{Si}^{SiC} + \mu_C^{SiC}$$

$$(n_{Si}^{SiC} = n_C^{SiC} = 1)$$

$$\begin{aligned} \Delta_f G_{SiC} &= \mu_{Si}^{SiC} + \mu_C^{SiC} - \mu_{Si}^o - \mu_C^o \\ &= \underbrace{(\mu_{Si}^{SiC} - \mu_{Si}^o)}_{II} + \underbrace{(\mu_C^{SiC} - \mu_C^o)}_I \end{aligned}$$


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(I) How does the chemical potential of C differ from its pure, reference state ?

It doesn't ! Pure C is in equilibrium with SiC

$$\mu_i^{SiC} = \mu_C^g = \mu_C^o$$



C atoms exchanging freely between SiC and C<sup>g</sup> via vapor phase  
 ↓  
 chemical equilibrium

(II) How does the chemical potential Si differ from its pure, reference state?

- If solid Si were present in the system, the partial pressure  $P_{Si}$  would be equal to its saturation value  $P_{Si}^{SAT}$
- Therefore  $\mu_{Si} - \mu_{Si}^o = RT \ln(P_{Si}/P_{Si}^{SAT})$ , recognizing that Si in SiC is in equilibrium with Si in vapor phase.

- What is  $P_{Si}$  ?

- Total pressure = 4.0 Pa
- C and SiC are saturated, but their saturation vapor pressure are negligible

$$P_{Si} \approx P = 4.0 \text{ Pa}, \quad \text{vapor is essentially pure Si}$$

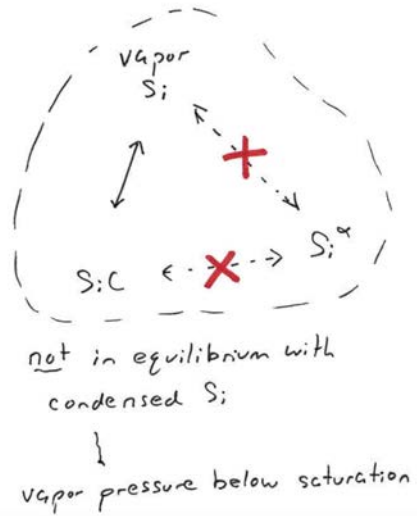
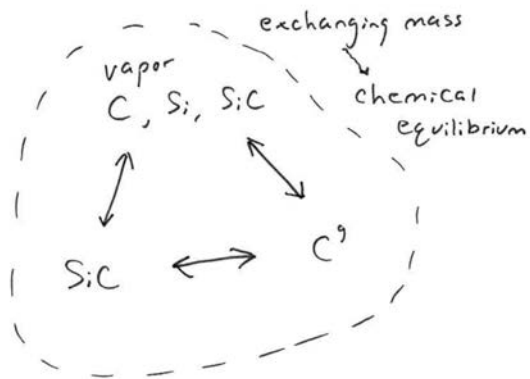
$$\mu_{Si} - \mu_{Si}^o = RT \ln\left(\frac{4.0}{4.4}\right) = -1,563 \text{ J/mol}$$

Therefore,

$$\begin{aligned} \Delta_f G_{SiC} &= (\mu_{Si} - \mu_{Si}^o) - \underbrace{(\mu_C - \mu_C^o)}_0 \\ &= RG \ln \frac{4.0}{4.4} \\ &= -1,563 \text{ J/mol} \end{aligned}$$

## 4 Key to solving such problems

Ask "Who is in equilibrium with whom??"



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